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10/776,203	02/12/2004	Rajiv Yadav Ranjan	50103-553	2760	
7590 01/14/2008 MCDERMOTT, WILL & EMERY			EXAMINER MCDONALD, RODNEY GLENN		
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Washington, Do	C 20005-3096		ART UNIT PAPER NUMBER		
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

		Annlination	Na	Applicant(a)				
		Application	NO.	Applicant(s)				
		10/776,203		RANJAN ET AL.				
Office Action S	ummary	Examiner		Art Unit	•			
		Rodney G. M		1795	_			
The MAILING DATE o Period for Reply	f this communication app	pears on the co	over sheet with the c	orrespondence address				
A SHORTENED STATUTOR WHICHEVER IS LONGER, - Extensions of time may be available to after SIX (6) MONTHS from the mailing If NO period for reply is specified aboomulated to reply within the set or extension and reply received by the Office later earned patent term adjustment. See	FROM THE MAILING D Inder the provisions of 37 CFR 1.1 Ing date of this communication. Indee, the maximum statutory period Indeed period for reply will, by statute Ithan three months after the mailin	DATE OF THIS 136(a). In no event, will apply and will exe, cause the applicat	COMMUNICATION however, may a reply be tim repire SIX (6) MONTHS from tion to become ABANDONE	I. the mailing date of this communication. D (35 U.S.C. § 133).				
Status								
1) Responsive to commu	nication(s) filed on 29 C	October 2007.						
2a) ☐ This action is FINAL .	This action is FINAL . 2b)⊠ This action is non-final.							
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is							
closed in accordance	with the practice under b	Ex parte Quay	<i>le</i> , 1935 C.D. 11, 45	i3 O.G. 213.				
Disposition of Claims			•	•				
4) ⊠ Claim(s) <u>1-4,6,7,11-13</u> 4a) Of the above claim 5) □ Claim(s) is/are 6) ⊠ Claim(s) <u>1-4,6,7,11-13</u> 7) □ Claim(s) is/are	(s) is/are withdra allowed. 3,15-17,20,21 and 23-32	wn from consi 2 is/are rejecte	deration. d.					
Application Papers								
9) The specification is obj	· ·							
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
				ected to. See 37 CFR 1.121(d).				
11) The oath or declaration								
Priority under 35 U.S.C. § 119								
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: Certified copies of the priority documents have been received. Certified copies of the priority documents have been received in Application No Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 								
Attachment(s)	903)	41	Interview Summary	(PTO-413)				
 Notice of References Cited (PTO- Notice of Draftsperson's Patent D 		4)	Paper No(s)/Mail Da	ite				
3) Information Disclosure Statement Paper No(s)/Mail Date	(s) (PTO/SB/08)	5) 6)	=	atent Application				

DETAILED ACTION

Drawings

The drawings were received on April 18, 2007. These drawings are acknowledged.

Claim Rejections - 35 USC § 112

Claim 26 is rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention. Specifically, it is unclear where in the specification there is support for utilizing changing magnet sizes in combination with changing target to substrate spacing. If there is support it is requested that Applicant point to the page and line number to show the support.

Claim 23 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claim 23 is indefinite because "the soft magnetic underlayer" lacks antecedent basis.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

10/776,203 Art Unit: 1795

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 24, 27, 28, 31 and 32 are rejected under 35 U.S.C. 102(b) as being anticipated by Akiyama et al. (Japan 2000-057640).

Regarding claims 1, 24, Akiyama et al. teach a cathode sputtering apparatus (Fig. 1) for forming a uniform thickness layer of a selected material on at least one workpiece in a multi-stage process comprising depositing a plurality of sub-layers. A first group of spaced-apart cathode target assemblies (i.e. chambers 2, 3) comprising annular-shaped magnetron magnet assemblies (i.e. magnet diameter of 160 mm and 200 mm). A transportation unit for transporting at least one workpiece past each target assembly of the first group of target assemblies for deposition of a first plurality of sublayers on a first surface of the at least one workpiece. (i.e. conveyance device for inline processing) Each target assembly of the first group of target assemblies comprises a sputtering surface oriented substantially parallel to the first surface of the at least one substrate. The first group of target assemblies adapted to provide sublayers with different sputtered film thickness profiles, such that the first plurality of sub-layers collectively form the uniform thickness layer of the selected material (i.e. thickness distribution suppressed to 5%). The annular-shaped magnetron magnet assemblies having progressively increasing diameters. (See Abstract; Machine Translation 0020; Machine Translation 0025; Machine Translation 0036) The size of the magnets are either decreased from largest to smallest or increased from smaller to largest. (Machine Translation 0025, 0036 respectively)

10/776,203 Art Unit: 1795

Regarding claims 27, 28, Akiyama et al. teach the outer diameter of the magnetron magnet to be 200 mm and 120 mm respectively. It would follow that the inner diameters would be less than 200 mm and less than 120 mm because of the showing in Fig. 2. (See Abstract; Fig. 2)

Regarding claims 31 and 32, Akiyama et al. teach the outer diameter of the magnetron magnet to be 200 mm and 120 mm respectively. It would follow that the inner diameters would be less than 200 mm and less than 120 mm because of the showing in Fig. 2. (See Abstract; Fig. 2)

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

10/776,203 Art Unit: 1795

Claims 1-4, 6, 7, 11, 13, 15-17, 20, 24, 25, 29 and 30 are rejected under 35 U.S.C. 103(a) as being unpatentable over Akiyama et al. (Japan 2000-057640) in view of Hedgcoth (U.S. Pat. 4,894,133).

Akiyama et al. is discussed above and all is as applies above. (See Akiyama et al. discussed above) Akiyama et al. applies to claims 1, 13 and 24. (See Akiyama et al. discussed above)

The differences between Akiyama et al. and the present claims is that rearranging the order of the magnets is not discussed (Claims 1, 13), a second set of targets to coat a second side of the substrate is not discussed (Claims 2, 13, 25), the cathode targets being in substantial vertical registry is not discussed (Claim 3, 15), the cathode/target assemblies of the first and second groups of cathode/target assemblies located within a single vacuum chamber is not discussed (Claim 4), the cathode/target assemblies of said first and second groups of cathode/target assemblies form an in-line or a circular-shaped arrangement within said vacuum chamber is not discussed (Claims 5. 16), the cathode/target assemblies of said first and second groups of cathode/target assemblies are located in a plurality of vacuum chambers is not discussed (Claims 6, 17), the plurality of vacuum chambers forming an in-line or a circularly-shaped arrangement of chambers is not discussed (Claim 7), each cathode/target assembly of said first and second groups of cathode/target assemblies is a planar magnetron cathode/target assembly including a magnetron magnet means is not discussed (Claims 8, 18), the magnetron magnet means of at least some of the planar magnetron cathode/target assemblies are of different lengths, widths or diameters is not discussed

10/776,203 Art Unit: 1795

(Claims 9) and the means for transporting the at least one substrate/workpiece past the first and second groups of cathode/target assemblies for deposition of the first, second pluralities of sub-layers comprises means for mounting and transporting at least one disk-shaped substrate/workpiece is not discussed (Claims 11, 20), forming perpendicular magnetic recording medium is not discussed (Claim 13) and the inner and outer diameter of the magnets are not discussed (Claims 29, 30).

Regarding claims 1, 13, As to reversing the order of the magnets it appears to the Examiner that Akiyama does suggest utilizing a smaller magnet than a larger magnet (See paragraph 0036) But however it would be obvious to reverse the sequence in the case where a larger magnet and then a smaller magnet is utilized (as seen in Machine Translation 0025) because in both instances a uniform total film will result. See Ex parte Rubin , 128 USPQ 440 (Bd. App. 1959) (Prior art reference disclosing a process of making a laminated sheet wherein a base sheet is first coated with a metallic film and thereafter impregnated with a thermosetting material was held to render prima facie obvious claims directed to a process of making a laminated sheet by reversing the order of the prior art process steps.). See also In re Burhans, 154 F.2d 690, 69 USPQ 330 (CCPA 1946) (selection of any order of performing process steps is prima facie obvious in the absence of new or unexpected results); In re Gibson, 39 F.2d 975, 5 USPQ 230 (CCPA 1930) (Selection of any order of mixing ingredients is prima facie obvious.)

Regarding claims 2, 13, 25, Hedgcoth teach providing targets to coat both sides of a substrate. (See Fig. 1; Column 4 lines 31-35)

10/776,203 Art Unit: 1795

Regarding claim 3, Hedgcoth suggest locating target in vertical registry for an inline apparatus. (See Figs. 1 and 2)

Regarding claim 4, Hedgcoth locating targets 42 in a single vacuum chamber. (See Figs. 1 and 2)

Regarding claim 6, Hedgcoth suggest locating targets 42 and 44 in different vacuum chambers. (See Figs. 1 and 2; Column 4 lines 7-8)

Regarding claim 7, Hedgcoth suggest the plurality of vacuum chamber arranged in-line. (See Figs. 1 and 2)

Regarding claim 11, Hedgcoth suggest means 6 for transporting and mounting at least one disk shaped workpiece. (Column 4 line 4; Fig. 2)

Regarding claim 13, Hedgcoth teach forming perpendicular magnetic recording medium. (Column 4 lines 56-57) It follows that to make a uniform layer one would use the teachings of Akiyama et al. when sputtering depositing layers such as when Hedgcoth sputters the magnetic recording layer.

Regarding claim 15, Hedgcoth suggest locating target in vertical registry. (See Figs. 1 and 2) Hedgcoth teach forming coatings on each of the first and second surface simultaneously. (See Figs. 1, 2)

Regarding claim 16, Hedgcoth suggest an in-line arrangement. (See Figs. 1 and 2)

Regarding claim 17, Hedgcoth suggest the plurality of vacuum chambers arranged in-line. (See Figs. 1 and 2)

10/776,203 Art Unit: 1795

Regarding claim 18, Hedgcoth suggest that the targets should be magnetron targets. (Column 4 lines 33-35; Column 4 lines 52-55)

Regarding claim 20, Hedgcoth suggest means 6 for transporting and mounting at least one disk shaped workpiece. (Column 4 line 4; Fig. 2)

The motivation for utilizing the features of Hedgcoth is that it allows for producing magnetic disks. (See Abstract)

Regarding claims 29, 30, Akiyama et al. teach the outer diameter of the magnetron magnet to be 200 mm and 120 mm respectively. It would follow that the inner diameters would be less than 200 mm and less than 120 mm because of the showing in Fig. 2. (See Abstract; Fig. 2)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have modified Kobayashi et al. by utilizing the features of Hedgcoth because it allows for producing magnetic disks.

Claims 12, 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Akiyama et al. in view of Hedgcoth as applied to claims 1-4, 6, 7, 11, 13, 15-17, 20, 24, 25, 29 and 30 above, and further in view of Mukai et al. (U.S. Pat. 5,441,615).

The difference not yet discussed is the use of shield members. (Claims 12, 21)

Regarding claims 12, 21, Mukai et al. teach utilizing deposition shield members for targets. (Column 3 lines 30-32)

The motivation for utilizing the features of Mukai et al. is that it allows for preventing sputtered particles from dispersing to the outside of the deposition shield members. (Column 2 lines 61-65)

10/776,203 Art Unit: 1795

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized the features of Mukai et al. because it allows for preventing sputtered particles from dispersing to the outside of the deposition shield members.

Claim 26 is rejected under 35 U.S.C. 103(a) as being unpatentable over Kobayashi et al. in view of Hedgcoth as applied to claims 1-4, 6, 7, 11, 13, 15-17, 20, 24, 25, 29 and 30 above, and further in view of Kobayashi et al. (Japan 56-152963).

The difference not yet discussed is using different spacing between the substrate and the target. (Claim 26)

Regarding claim 26, Kobayashi et al. teach a cathode sputtering apparatus and method for forming a uniform thickness layer on at least one surface of at least one workpiece in a multi-stage process comprising deposition of a plurality of sub-layers. Kobayashi et al. teach a first group of spaced apart cathode/target assemblies 15, 16. The substrate is moved to be concentric with each of the targets. Each cathode/target assembly is oriented to be substantially parallel to the first surface of the substrate. The group of cathodes 15, 16 is adapted to provide sublayers with different sputtered film thickness profiles, such the sublayers form a uniform thickness profile. In order to achieve the uniform thickness profile the cathode/target assemblies are placed at different distances from the substrate. (See Abstract; Fig. 4; Fig. 5)

The motivation for utilizing the features of Kobayashi et al. is that it allows for forming a uniform film layer. (See Abstract)

10/776,203 Art Unit: 1795

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized the features of Kobayashi et al. because it allows for forming a uniform layer.

Claim 23 is rejected under 35 U.S.C. 103(a) as being unpatentable over
Kobayashi et al. in view of Hedgcoth as applied to claims 1-4, 6, 7, 11, 13, 15-17, 20,
24, 25, 29 and 30 above, and further in view of Nasu et al. (U.S. Pat. 5,326,637).

The difference not yet discussed is depositing a perpendicular magnetic recording medium on a magnetically soft underlayer and the magnetic soft underlayer being 500 to 4,000 Angstroms and being Fe or Fe-Co (claim 23).

Regarding claim 23, Nasu et al. teach depositing a magnetic recording medium by sputtering on a magnetically soft underlayer. (See Abstract) The magnetic soft underlayer can be Fe, Fe-Co. (See Abstract). The thickness can be 500 Angstroms. (Column 5 lines 28-35)

The motivation for utilizing the features of Nasu et al. is that it allows for producing a film with high recording density and reproduction output. (See Abstract)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized the features of Nasu et al. because it allows for producing a film with high recording density and reproduction output.

Response to Arguments

Applicant's arguments filed October 29, 2007 have been fully considered but they are not persuasive.

10/776,203 Art Unit: 1795

In response to the argument that Kobayashi is silent regarding the annularly shaped cathode/target assemblies having progressively increasing diameters, it is argued that newly cited reference to Akiyama teach utilizing magnets having diameters behind targets that either increase in diameter or decrease in diameter in order to form a uniform film. The thin film thickness can be suppressed to 5% or less. The magnets are annular due to the discussion of the diameters. (See Machine translation paragraph 0025 and paragraph 0036)

In response to the argument that Kobayashi do not teach an annularly-shaped cathode/target assembly, it is argued that the claims require the cathode/target assemblies to have annular-shaped magnetron magnet assemblies. Newly cited reference to Akiyama et al. teach annular magnet assemblies for sputtering cathodes that have diameters of 200 mm and 120 mm. (See Akiyama et al. Abstract)

In response to the argument that Nasu teach away from forming an about 500 to about 4,000 Angstrom thick layer of soft magnetic material, it is argued that Nasu teach utilizing 500 Angstroms which is a point required by the claims. Where the range of the prior art touches the range claimed the point anticipates the claim. (See Nasu discussed above)

This action will be made NON-Final based on the newly cited reference.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Rodney G. McDonald whose telephone number is 571-272-1340. The examiner can normally be reached on M-Th with every Friday off..

10/776,203 Art Unit: 1795

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nam X. Nguyen can be reached on 571-272-1342. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Rodney G. McDonald Primary Examiner

Art Unit 1795

RM January 8, 2008